Date: 13.05.2025

An Institute of National Importance Specialized in IT Enabled Design and Manufacturing Chennai - 600127

Advertisement for the Post of Research Associate I

Advt. No.:IIITDMK/PR/RAI/A12/2025

Applications are invited for the following post. The post is purely on a contractual basis.

Name of Position	Research Associate I				
Number of Positions	One				
Nature of Work	Research & Trilateral country collaboration				
Duration of the Position	The position is temporary for one year, with the possibility of a one- year extension based on a performance review. This project presents an exciting opportunity to collaborate with the University of Malaya, Malaysia, and Universitas Indonesia, Indonesia, in a highly interdisciplinary research environment.				
Stipend	Rs. 58,000/- pm + 24% HRA (Fixed) Note: 24% HRA will be paid if no accommodation is provided by the Institute.				
Title of the Sponsored Project	Next-Generation Thermoelectric Textiles: Pioneering the future of Wearable Technology				
Funding Agency	ANRF AISTDF				
P.I / Co-P.I	Dr. Pandiyarasan Veluswamy				
Department	Electronics and Communication Engineering				
Educational Qualification	 Candidate who have submitted their thesis and are awaiting the award of a Ph.D degree may also apply. Candidates should provide evidence of having conducted high-quality research during or after their Ph. D. program. Proven experience in high-quality wet-lab materials such as intermetallics, spinel, and transition metal oxides. Hands-on expertise in transport measurements like Seebeck and Electrical Coefficient, Thermal Conductivity, or Physical Property Measurement System (PPMS). Proficiency in analyzing data from X-ray diffraction, Scanning electron microscopy, Transmission electron microscopy with SAED, UV and FTIR Spectroscopy, Hall measurements, and XPS experiments. Additional consideration will be given to candidates with experience in simulations as Density Functional Theory (DFT) calculations. Should have experience working in a group collaboration. 				

Additional Qualification (Desirable, if any)	Proven experimental research in thermoelectric and proficiency in analyzing data from XRD, SEM, XPS, TC, TEM-SAED and wet chemical lab experiments.
Age Limit	30 years as on Last date of receiving the application (Age relaxation is applicable as per Gol norms)
Interview Schedule: Date, Time & Venue	Shortlisted candidates shall be informed through email. 06, June 2025, 10 AM. IIITDM Kancheepuram, Chennai, Admin Building
Last Date	03-06-2025

How to Apply and Selection Procedure:

- 1. Interested candidates are requested to submit their applications in the enclosed prescribed format.
- Take print of the application form, fill, sign, and scan the application form.
 Upload the scanned copy in google form link:
 https://forms.gle/9okPRbZXoo3Kuj3CA and submit the hard copy at the time of Interview.
- 3. Candidates should be present physically at IIITDM Kancheepuram located at Chennai 600127 for the written test and/or interview on June 6, 2025 at 10am.
- 4. Candidates should produce all educational and experience certificates at the time of interview for verification.
- 5. No TA/DA will be paid for attending the interview.
- 6. The selection process consists of written test followed by Interview. The topic forwritten test along with syllabus is enclosed.

For any clarification regarding the application process, the candidate may contact the PI. email: pandiyarasan@iiitdm.ac.in

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Topics for Written Test

- 1. Thermoelectric and Thermomagnetic phenomena
- 2. Figure of Merit
- 3. Efficiency of Thermoelectric Power Generators
- 4. Transport of Heat and Electricity in Solids
- 5. Band Theory of Solids
- 6. Influence of carrier concentration on the properties of a Semiconductor
- 7. Optimization of Electronic Properties and Minimizing Thermal Conductivity
- 8. Measurement and Characterizations: XRD, SEM, UV, FTIR, XPS, PPM

1. Name (in block letters)):					Insert pa				
2. Date of Birth (DD/MM/YY):						size photograph (image file)				
3. Address for Commun	nication:		Permanent Address:							
City:Pin:			City:Pin:							
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*Email:										
*Please make sure that th	e e-mail ID is correct an	d legible.								
4.Details of University/		10 th onward	s, insert cells if nec							
Degree / Examination Passed	Subjects/Area of specilaization	Institution		Year of Passing		verage ks/CGPA	Class			
5.Additional Qualifying	g Examination(s) Passo	ed (if any):								
(a) CSIR/UGC- NET-JRF			(b) JEST/GATE							
Registration/Roll No.:			Registration/Roll No.:							
Date of exam:			Score (percentile and Rank):							
Valid till:			Valid till:							

6.Experience (Teaching/Research/Industrial etc.) if any (insert cells if necessary): Period Name of the Designation Nature of Work From To Organization 7. Research Publications (if any, submitted/accepted/published): Please also write your contribution in the published articles. Kindly attach the list of publications and conferences as separate list in annexure 1. 8. If you have prior experience working in the area of experimental materials and devices for thermoelectric applications, please write about it in about 200 words. 9. References: Please provide us details (Name, Affiliations, email ID, phone number, and relationship with you) of at least two referees who will be able to write a reference letter for you.

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Mothe	r's/Father's/Spouse's	Name					
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Wheth	er belongs to reserved	l category: SC/ST	/OBC				
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